AC6328B Datasheet

Zhuhai Jieli Technology Co.,LTD

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AC6328B Features

High performance 32-bit RISC CPU

- RISC 32-bit CPU
- DC-96MHz operation
- 73KB data RAM
- 8KB I-cache 2way
- 1KB Rocache 1way
- 64 Vectored interrupts
- 8 Levels interrupt priority

Flexible I/O

- 2 GPIO pins
- All GPIO pins can be programmable as input or output individually
- All GPIO pins are internal pull-up/pull-down selectable individually
- CMOS/TTL level schmitt triggered input
- External wake up/interrupt on all GPIOs

Peripheral Feature

- One Full Speed USB OTG controller
- One full-duplex advanced UART(DMA)
- One IIC interface supports host and device mode
- 2 channels 10-bit ADC
- 1 channel 8 levels Low Power Detector
- Embedded PMU support low power mode
- Watchdog
- Power-on reset

Bluetooth Feature

- CMOS single-chip fully-integrated radio and baseband
- Compliant with Bluetooth
- V5.0+BR+EDR+BLE specification
- Bluetooth Piconet and Scatternet support
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides +8dbm transmitting power
- Receiver with -92dBm sensitivity
- Support

 a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap\
 gatt\rfcomm\sdp\l2cap profile

Power Supply

- **VBAT** is 1.8V to 5.5V
- VDDIO is 1.8V to 3.4V

Packages

SOP8

Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65°C to +150°C

1. Block Diagram

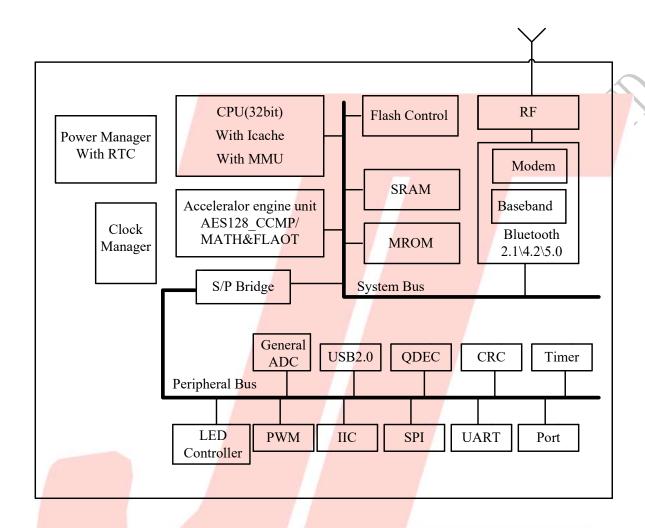


Figure 1-1 AC6328B_SOP8 Block Diagram

2. Pin Definition

2.1 Pin Assignment

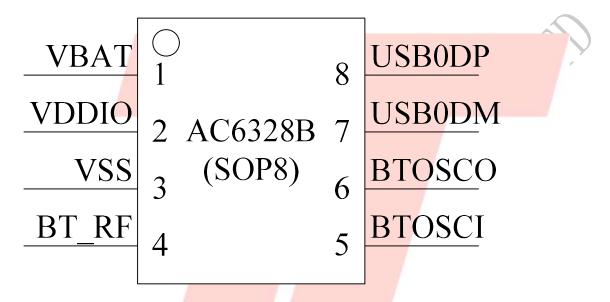


Figure 2-1 AC6328B_SOP8 Package Diagram

2.2 Pin Description

Table 2-1 AC6328B_SOP8 Pin Description

PIN NO.	Name	I/O Type	Function	Other Function
1	VBAT	P	LDO Power	-
2	VDDIO	P	IO Power 3.3V	-
3	VSS	P	GND	-
4	BT_RF	-	RF Antenna	-
5	BTOSCI	I	BTOSCI	-
6	BTOSCO	О	BTOSCO	-
7	USB0DM	I/O	GPIO (pull down)	IIC_SDA_A: IIC SDA(A); ADC11: ADC Channel 11; UART1_RXD: Uart1 Data In(D);
8	USB0DP	I/O	GPIO (pull down)	IIC_SCL_A: IIC SCL(A); ADC10: ADC Channel 10; UART1_TXD: Uart1 Data Out(D);



3. Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	5.5	V
V _{VDDIO}	3.3V IO Input Voltage	-0.3	3.6	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 Recommended Operating Conditions

Table 3-2

Symbol	Parameter	Min	Тур	Max	Unit		Test Conditions
VBAT	Voltage Input	1.8	3.7	5.5	V		_
VDDIO	Voltage Input	/ -	3.0	7 +	V	- 4	
I _{VDDIO}	Loading current	-	-	60	mA	1	VBAT = 4.2V

3.3 IO Input/Output Electrical Logical Characteristics

Table 3-3

IO input ch	aracteristics					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V_{IL}	Low-Level Input Voltage	-0.3	_	0.3* VDDIO	V	VDDIO = 3.3V
Vін	High-Level Input Voltage	0.7* VDDIO	_	VDDIO+0.3	V	VDDIO = 3.3V
IO output c	haracteristics					
V _{OL}	Low-Level Output Voltage	-	-	0.33	V	VDDIO = 3.3V
V _{OH}	High-Level Output Voltage	2.7	_	_	V	VDDIO = 3.3V

3.4 Internal Resistor Characteristics

Table 3-4

Port	Drive Strength	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
USB0DP	4mA	1.5K	15K	USB0DM&USB0DP default pull down
USB0DM	4mA	180K	15K	2. Internal pull-up/pull-down resistance accuracy ±20%

3.5 BT Characteristics

3.5.1 Transmitter

Basic Data Rate

Table 3-5

Dasic Data Rate			Table 3-	3		
Paramete	r	Min	Тур	Max	Unit	Test Conditions
RF Transmit P	ower		4	6	dBm	
RF Power Contro	l Range		20		dB	25°C,
20dB Bandwi	idth		950		KHz	Power Supply
	+2MHz		-40		dBm	
Adjacent Channel	-2MHz		-38		dBm	VDDIO=3.3V
Transmit Power	+3MHz		-44		dBm	2441MHz
	-3MHz		-35		dBm	

Enhanced Data Rate

Table 3-6

Paramete	Min	Тур	Max	Unit	Test Conditions	
Relative Power			-1		dB	
π/4 DQPSK	DEVM RMS		6		%	
1 2 1	DEVM 99%		10		%	25°C,
Modulation Accuracy	DEVM Peak		15		%	Power Supply
	+2MHz		-40		dBm	VDDIO=3.3V
Adjacent Channel	-2MHz		-38		dBm	2441MHz
Transmit Power	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

3.5.2 Receiver

Basic Data Rate

Table 3-7

Parameter	Min	Тур	Max	Unit	Test Conditions
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Sensitivit		-92	dBm		
SCHSILIVIL	<u>y</u>	 	-72	 uDIII	1
Co-channel Interference Rejection			-13	dB	
	+1MHz		+5	dB	25°C,
	-1MHz		+2	dB	Power Supply
Adjacent Channel	+2MHz		+37	dB	VDDIO=3.3V
Interference Rejection	-2MHz		+36	dB	2441MHz
1	+3MHz		+40	dB	
	-3MHz		+35	dB	

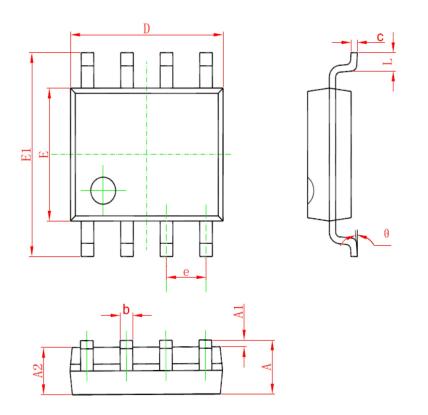
Enhanced Data Rate

Table 3-8

Paramete	Min	Тур	Max	Unit	Test Conditions	
Sensitivity			-92		dBm	
Co-channel Interferer	nce Rejection		-13		dB	
	+1MHz	/	+5		dB	25°C,
	-1MHz		+2		dB	Power Supply
Adjacent Channel	+2MHz		+37		dB	VDDIO=3.3V
Interference Rejection	-2MHz		+36		dB	2441MHz
	+3MHz		+40		dB	
	-3MHz		+35		dB	

4. Package Information

4.1 SOP8



Symbol	Dimension I	n Millimeters	Dimensio	n In Inches
Syllibol	Min	Max	Min	Max
Α	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
е	1.27	TYP	0.05	0TYP
L	0.400	1.270	0.016	0.050
θ	00	8 ⁰	00	8 ⁰

Figure 4-1 AC6328B_SOP8 Package

5. Package Type Specification



- ①Represents different packages
- ②Represents different memory sizes
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash

6. Revision History

Date	Revision	Description
2021.05.19	V1.0	Initial Release